

Problem statement Mini Project, Analog IC Lab (ECP316)

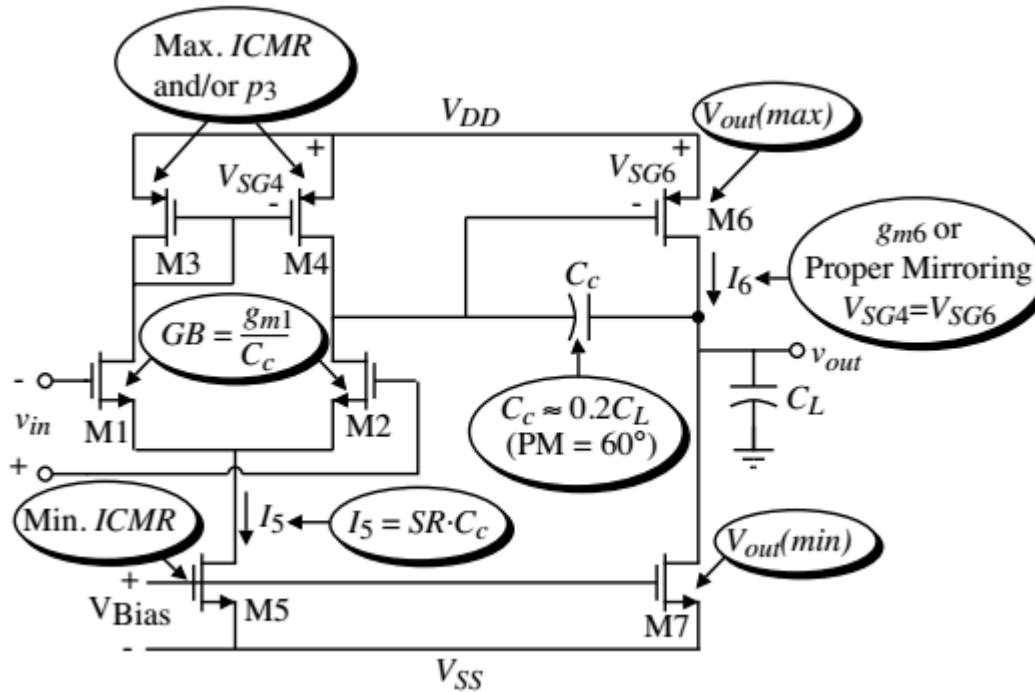
Two-Stage Operational Amplifier at 1 μm technology.

If $K_N' = 120 \mu\text{A}/\text{V}^2$, $K_P' = 25 \mu\text{A}/\text{V}^2$, $V_{TN} = |V_{TP}| = 0.5$, $\lambda_n = 0.06 \text{V}^{-1}$, and $\lambda_p = 0.08 \text{V}^{-1}$, Design a two-stage, CMOS op amp that meets the following specifications. Assume the channel length is to be $1 \mu\text{m}$ and the load capacitor is $C_L = 10 \text{pF}$.

Note: For $1 \mu\text{m}$ design consider the standard model used in the lab.

$A_v > 3000 \text{V/V}$	$V_{DD} = 2.5 \text{V}$	$GB = 5 \text{MHz}$	$SR > 10 \text{V}/\mu\text{s}$
60° phase margin	$0.5 \text{V} < V_{out} \text{ range} < 2 \text{V}$	$ICMR = 1.25 \text{V to } 2 \text{V}$	$P_{diss} 2 \text{mW}$

The useful formula and tentative circuit diagram for calculation unknown parameters is described below:



- Calculate sizing of each transistor and mention the values in the final circuit.
- AC Response (dB vs Frequency)
- Transient Response
- Prepare the table for obtained simulated results vs given specification.